Bus Buffer Gate with 3-state Output

HITACHI

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Description

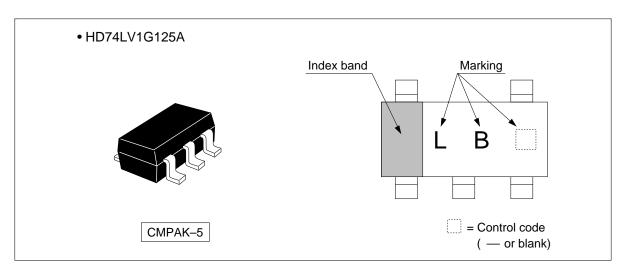
The HD74LV1G125A has a bus buffer gate with 3–state output in a 5 pin package. Output is disabled when the associated output enable (\overline{OE}) input is high. To ensure the high impedance state during power up or power down, \overline{OE} should be connected to V_{CC} through a pull-down resistor; the minimum value of the resistor is determined by the current souring capability of the driver. Low voltage and high speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

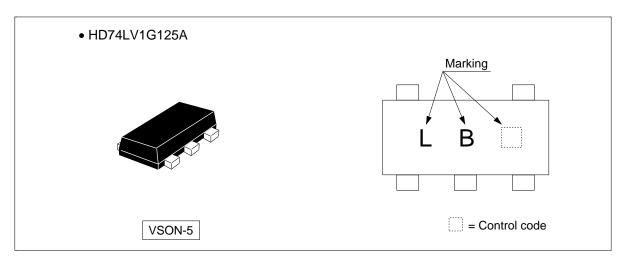
Features

- The basic gate function is lined up as hitachi uni logic series.
- Supplied on emboss taping for high speed automatic mounting.
- Electrical characteristics equivalent to the HD74LV125A Supply voltage range: 1.65 to 5.5 V
 Operating temperature range: -40 to +85°C
- All inputs V_{IH} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V) All outputs V_{O} (Max.) = 5.5 V (@ V_{CC} = 0 V, Output : Z)
- Output current ± 6 mA (@V_{CC} = 3.0 V to 3.6 V), ± 12 mA (@V_{CC} = 4.5 V to 5.5 V)
- All the logical input has hysteresis voltage for the slow transition.



Outline and Article Indication





Function Table

Inputs		Output Y	
ŌĒ	Α		
L	Н	н	
L	L	L	
H	Х	Z	

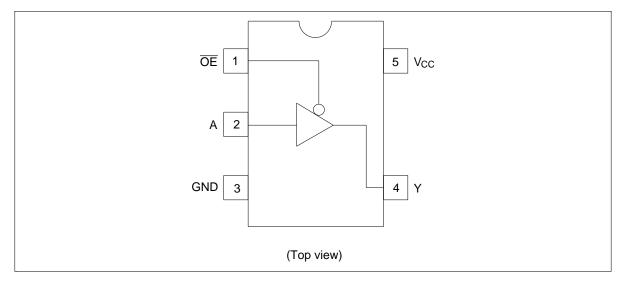
H : High level

L : Low level

X : Immaterial

Z : High impedance

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	V _{cc}	–0.5 to 7.0	V	
Input voltage range *1	V _I	-0.5 to 7.0	V	
Output voltage range *1,2	Vo	-0.5 to $V_{CC} + 0.5$	V	Output : H or L
		-0.5 to 7.0		V _{cc} : OFF or Output : Z
Input clamp current	I _{IK}	-20	mA	V ₁ < 0
Output clamp current	I _{OK}	±50	mA	$V_{o} < 0 \text{ or } V_{o} > V_{cc}$
Continuous output current	Io	±25	mA	$V_{\rm o}$ = 0 to $V_{\rm cc}$
Continuous current through V _{cc} or GND	I _{CC} or I _{GND}	±50	mA	
Maximum power dissipation at Ta = 25°C (in still air) '3	P _T	200	mW	
Storage temperature	Tstg	-65 to 150	°C	

Notes:

The absolute maximum ratings are values which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150° C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V _{cc}	1.65	5.5	V	
Input voltage range	V _I	0	5.5	V	"
Output voltage range	V _o	0	V _{cc}	V	
		0	5.5		Output : Z
Output current	I _{OL}	_	1	mA	V_{cc} = 1.65 to 1.95 V
		_	2		V_{cc} = 2.3 to 2.7 V
		_	6		$V_{cc} = 3.0 \text{ to } 3.6 \text{ V}$
		_	12		V_{cc} = 4.5 to 5.5 V
	I _{OH}	_	-1		V_{cc} = 1.65 to 1.95 V
		_	-2		V_{cc} = 2.3 to 2.7 V
		_	-6		V_{cc} = 3.0 to 3.6 V
		_	-12		V_{cc} = 4.5 to 5.5 V
Input transition rise or fall rate	Δt / Δν	0	300	ns / V	V_{cc} = 1.65 to 1.95 V
		0	200		V_{cc} = 2.3 to 2.7 V
		0	100		$V_{cc} = 3.0 \text{ to } 3.6 \text{ V}$
		0	20		$V_{cc} = 4.5 \text{ to } 5.5 \text{ V}$
Operating free-air temperature	T _a	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

Electrical Characteristic

• $Ta = -40 \text{ to } 85^{\circ}C$

Item	Symbol	V _{cc} (V) *	Min	Тур	Max	Unit	Test condition
Input voltage	V _{IH}	1.65 to 1.95	V _{cc} ×0.75	_	_	V	
		2.3 to 2.7	V _{cc} ×0.7	_	_	_	
		3.0 to 3.6	V _{cc} ×0.7	_	_	-	
		4.5 to 5.5	V _{cc} ×0.7		_	_	
	V _{IL}	1.65 to 1.95	_	_	V _{cc} ×0.25	_	
		2.3 to 2.7	_	_	V _{cc} ×0.3	=	
		3.0 to 3.6	_		V _{cc} ×0.3	_	
		4.5 to 5.5	_	_	V _{cc} ×0.3	_	
Hysteresis voltage	V _H	1.8	_	0.25	_	V	$V_T^+ - V_T^-$
		2.5		0.30		_	
		3.3	_	0.35	_	_	
		5.0	_	0.45	_	_	
Output voltage	V _{OH}	Min to Max	V _{cc} -0.1			V	$I_{OH} = -50 \ \mu A$
		1.65	1.4	_		_	$I_{OH} = -1 \text{ mA}$
		2.3	2.0			_	$I_{OH} = -2 \text{ mA}$
		3.0	2.48			_	$I_{OH} = -6 \text{ mA}$
		4.5	3.8		_	_	I _{OH} = -12 mA
	V _{OL}	Min to Max	_		0.1	_	I _{OL} = 50 μA
		1.65	_		0.3	_	I _{OL} = 1 mA
		2.3	_		0.4	_	I _{OL} = 2 mA
		3.0	_		0.44	_	I _{OL} = 6 mA
		4.5	_	_	0.55	-	I _{OL} = 12 mA
Input current	I _{IN}	0 to 5.5	_		±1	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Off state output current	I _{oz}	Min to Max		_	±5	μΑ	$V_0 = 5.5 \text{ V or GND}$
Quiescent supply current	I _{cc}	5.5	_		10	μΑ	$V_{IN} = V_{CC}$ or GND, $I_{O} = 0$
Output leakage current	I _{OFF}	0		_	5	μΑ	V_{IN} or $V_O = 0$ to 5.5 V
Input capacitance	C _{IN}	3.3	_	3.0	_	pF	$V_{IN} = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

• $V_{CC} = 1.8 \pm 0.15 V$

Item	Symbol	$T_a = 2$	$T_a = 25^{\circ}C$		$T_a = -40 \text{ to } 85^{\circ}\text{C}$		Unit	Test	FROM	ТО
		Min	Тур	Max	Min	Max	_	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	13.5	23.5	1.0	26.0	ns	C _L = 15 pF	Α	Υ
delay time	$t_{\tiny PHL}$	_	19.0	33.0	1.0	36.0	_	C _L = 50 pF	_	
Enable time	t _{zH}	_	13.7	26.5	1.0	29.0	ns	C _L = 15 pF	ŌĒ	Υ
	t_{zL}	_	20.5	36.0	1.0	38.0		C _L = 50 pF		
Disable time	t _{HZ}	_	8.3	20.0	1.0	22.5	ns	C _L = 15 pF	ŌĒ	Υ
	\mathbf{t}_{LZ}	_	13.0	29.5	1.0	32.0		C _L = 50 pF	_	

• $V_{CC} = 2.5 \pm 0.2 \text{ V}$

Item	Symbol	$T_a = 25^{\circ}C$		$T_a = -40 \text{ to } 85^{\circ}\text{C}$		Unit	Test	FROM	то	
		Min	Тур	Max	Min	Max	_	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	6.8	13.0	1.0	15.5	ns	C _L = 15 pF	Α	Υ
delay time	$t_{\tiny PHL}$	_	8.7	16.5	1.0	18.5	_	C _L = 50 pF	_	
Enable time	t _{zH}	_	7.0	13.0	1.0	15.5	ns	C _L = 15 pF	ŌĒ	Υ
	t_{ZL}	_	8.8	16.5	1.0	18.5	_	C _L = 50 pF	_	
Disable time	t _{HZ}	_	5.1	14.7	1.0	17.0	ns	C _L = 15 pF	ŌĒ	Υ
	$\mathbf{t}_{\scriptscriptstyle{LZ}}$	_	7.3	18.2	1.0	20.5	_	C _L = 50 pF	_	

• $V_{CC} = 3.3 \pm 0.3 \text{ V}$

Item	Symbol	$T_a = 2$	25°C		$T_a = -40 \text{ to } 85^{\circ}\text{C}$		Unit	Test	FROM	ТО
		Min	Тур	Max	Min	Max		Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	4.8	8.0	1.0	9.5	ns	C _L = 15 pF	Α	Υ
delay time	$t_{\tiny PHL}$	_	6.1	11.5	1.0	13.0		C _L = 50 pF		
Enable time	t _{zH}	_	4.8	8.0	1.0	9.5	ns	C _L = 15 pF	ŌĒ	Υ
	$\mathbf{t}_{\scriptscriptstyle ZL}$	_	6.2	11.5	1.0	13.0		C _L = 50 pF	_	
Disable time	t _{HZ}	_	4.1	9.7	1.0	11.5	ns	C _L = 15 pF	ŌĒ	Υ
	\mathbf{t}_{LZ}	_	5.5	13.2	1.0	15.0		C _L = 50 pF	_	

Switching Characteristics (cont)

•
$$V_{CC} = 5.0 \pm 0.5 \text{ V}$$

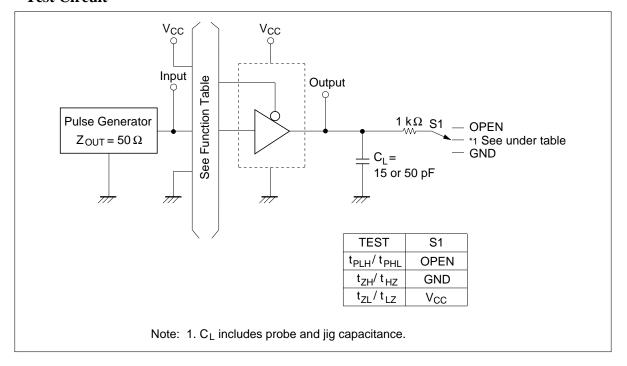
Item	Symbol	$T_a = 2$	25°C		$T_a = -40 \text{ to } 85^{\circ}\text{C}$		Unit	Test	FROM	ТО
		Min	Тур	Max	Min	Max	_	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	3.4	5.5	1.0	6.5	ns	C _L = 15 pF	Α	Υ
delay time	$t_{\tiny PHL}$	_	4.3	7.5	1.0	8.5		C _L = 50 pF	_	
Enable time	t _{zH}	_	3.4	5.1	1.0	6.0	ns	C _L = 15 pF	ŌĒ	Υ
	t_{zL}	_	4.4	7.1	1.0	8.0		C _L = 50 pF	_	
Disable time	t _{HZ}	_	3.2	6.8	1.0	8.0	ns	C _L = 15 pF	ŌĒ	Υ
	$\mathbf{t}_{\scriptscriptstyleLZ}$	_	4.0	8.8	1.0	10.0		C _L = 50 pF	_	

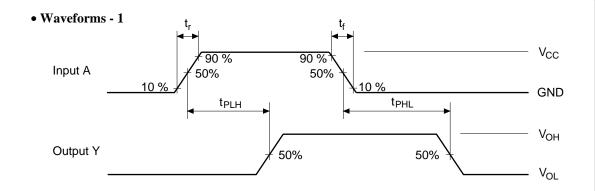
Operating Characteristics

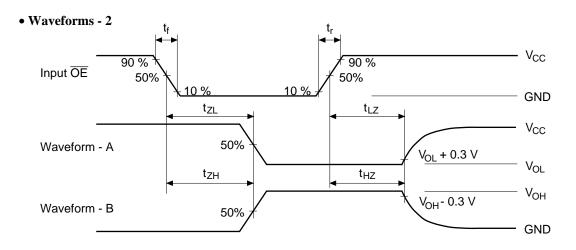
• $C_L = 50 \text{ pF}$

Item	Symbol	V _{cc} (V)	$T_a = 25$	$T_a = 25^{\circ}C$			Test Conditions
			Min	n Typ Max		<u> </u>	
Power dissipation capacitance	C_{PD}	3.3	_	10.5	_	pF	f = 10 MHz
		5.0	_	11.5	_		

Test Circuit

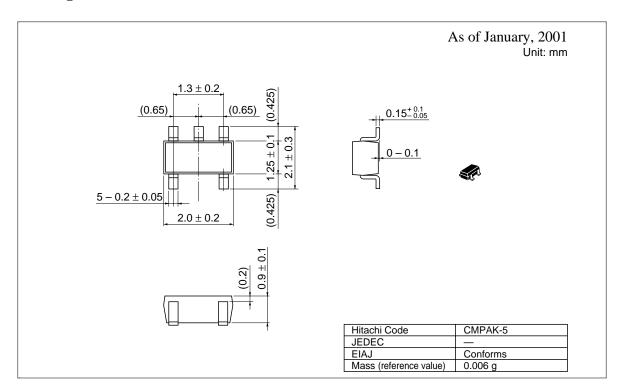


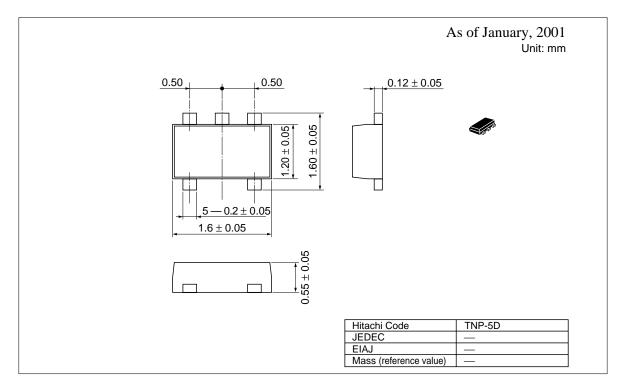




- Notes: 1. Input waveform : PRR \leq 1 MHz, Zo = 50 Ω , $t_r \leq$ 3 ns, $t_f \leq$ 3 ns.
 - 2. Waveform A is for an output with internal conditions such that the output is low except when disabled by the output control.
 - 3. Waveform B is for an output with internal conditions such that the output is high except when disabled by the output control.
 - 4. The output are measured one at a time with one transition per measurement.

Package Dimensions





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